



PATENT

Case Docket No. MICRON.061DV1

Date: March 19, 2001

Page 1

In re application of : Ahmad  
App. No. : 09/397,952  
Filed : September 17, 1999  
For : FABRICATION OF  
INTEGRATED DEVICES  
USING NITROGEN  
IMPLANTATION  
Examiner : Stephen H. Rao  
Art Unit : 2814

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on

March 19, 2001

(Date)  
*Adeel S. Akhtar*  
Adeel S. Akhtar, Reg. No. 41,349

TECHNOLOGY CENTER 2800

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ASSISTANT COMMISSIONER FOR PATENTS BOX AF  
WASHINGTON, D.C. 20231

Sir:

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated as shown below:

CLAIMS AS FILED						
	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NO. PREVIOUSLY PAID FOR	PRESENT EXTRA	RATE	ADDITIONAL FEE
Total Claims	21	—	21	= 0 ×	\$18	= \$0
Independent Claims	4	—	4	= 0 ×	\$80	= \$0
If application has been amended to contain multiple dependent claim(s), then add					\$270	= \$0
Time Extension Fee						\$0
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT						\$0

(X) Return prepaid postcard.

(X) Please charge any additional fees, including any fees for additional extension of time, or credit overpayment to Deposit Account No. 11-1410. A duplicate copy of this sheet is enclosed.

*Adeel S. Akhtar*

Adeel S. Akhtar  
Registration No. 41,349  
Attorney of Record

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T. Yaw  
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) Group Art Unit 2814

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(Date)

Adeel S. Akhtar, Reg. No. 41,349

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Dear Sir:

### In the Claims:

1. (Twice Amended) A process of forming a gate structure on a semiconductor substrate, comprising:

-1-